

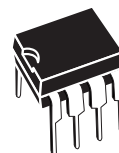


# M93C86, M93C76, M93C66 M93C56, M93C46

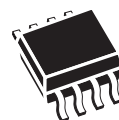
16 Kbit, 8 Kbit, 4 Kbit, 2 Kbit and 1 Kbit (8-bit or 16-bit wide)  
MICROWIRE® serial access EEPROM

## Features

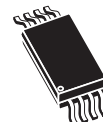
- Industry standard MICROWIRE bus
- Single supply voltage:
  - 4.5 V to 5.5 V for M93Cx6
  - 2.5 V to 5.5 V for M93Cx6-W
  - 1.8 V to 5.5 V for M93Cx6-R
- Dual organization: by word (x16) or byte (x8)
- Programming instructions that work on: byte, word or entire memory
- Self-timed programming cycle with auto-erase: 5 ms
- READY/ $\overline{\text{BUSY}}$  signal during programming
- 2 MHz clock rate
- Sequential read operation
- Enhanced ESD/latch-up behavior
- More than 1 million write cycles
- More than 40 year data retention
- Packages
  - SO8, TSSOP8, UDFPN8 packages: RoHS-compliant and Halogen-free (ECOPACK2®)
  - PDIP8 package: RoHS-compliant (ECOPACK1®)



PDIP8 (BN)



SO8 (MN)  
150 mil width



TSSOP8 (DW)  
169 mil width



UDFPN8 (MB or MC)  
2 x 3 mm (MLP)

**Table 1. Device summary**

| Part number | Memory size | Supply voltage | Part number | Memory size | Supply voltage | Part number | Memory size | Supply voltage |
|-------------|-------------|----------------|-------------|-------------|----------------|-------------|-------------|----------------|
| M93C46      | 1 Kbit      | 4.5 V to 5.5 V | M93C66      | 4 Kbits     | 4.5 V to 5.5 V | M93C86      | 16 Kbits    | 4.5 V to 5.5 V |
| M93C46-W    |             | 2.5 V to 5.5 V | M93C66-W    |             | 2.5 V to 5.5 V | M93C86-W    |             | 2.5 V to 5.5 V |
| M93C56      | 2 Kbits     | 4.5 V to 5.5 V | M93C66-R    |             | 1.8 V to 5.5 V |             |             |                |
| M93C56-W    |             | 2.5 V to 5.5 V | M93C76-W    | 8 Kbits     | 2.5 V to 5.5 V |             |             |                |
| M93C56-R    |             | 1.8 V to 5.5 V | M93C76-R    |             | 1.8 V to 5.5 V |             |             |                |

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# 1 Description

The M93C46 (1 Kbit), M93C56 (2 Kbit), M93C66 (4 Kbit), M93C76 (8 Kbit) and M93C86 (16 Kbit) are electrically erasable programmable memory (EEPROM) devices accessed through the MICROWIRE bus protocol.

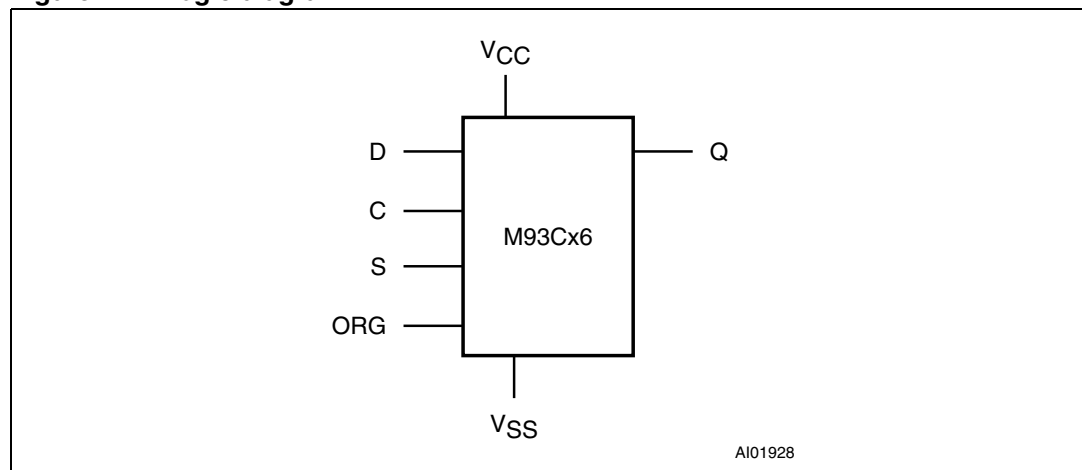
M93Cx6 devices operate within a voltage supply range from 4.5 V to 5.5 V, M93Cx6-W devices operate within a voltage supply range from 2.5 V to 5.5 V and M93Cx6-R devices operate within a voltage supply range from 1.8 V to 5.5 V.

The memory array can be configured either in bytes (x8b ) or words (x16b).

**Table 2. Memory size versus organization**

| Device | Number of bits | Number of 8-bit bytes | Number of 16-bit words |
|--------|----------------|-----------------------|------------------------|
| M93C86 | 16384          | 2048                  | 1024                   |
| M93C76 | 8192           | 1024                  | 512                    |
| M93C66 | 4096           | 512                   | 256                    |
| M93C56 | 2048           | 256                   | 128                    |
| M93C46 | 1024           | 128                   | 64                     |

**Figure 1. Logic diagram**



**Table 3. Signal names**

| Signal name     | Function            | Direction |
|-----------------|---------------------|-----------|
| S               | Chip Select         | Input     |
| D               | Serial Data input   | Input     |
| Q               | Serial Data output  | Output    |
| C               | Serial Clock        | Input     |
| ORG             | Organization Select | Input     |
| V <sub>CC</sub> | Supply voltage      |           |
| V <sub>SS</sub> | Ground              |           |

The M93Cx6 is accessed by a set of instructions, as summarized in [Table 4](#), and in more detail in [Table 5: Instruction set for the M93C46](#) to [Table 7: Instruction set for the M93C76 and M93C86](#)).

**Table 4. Instruction set for the M93Cx6**

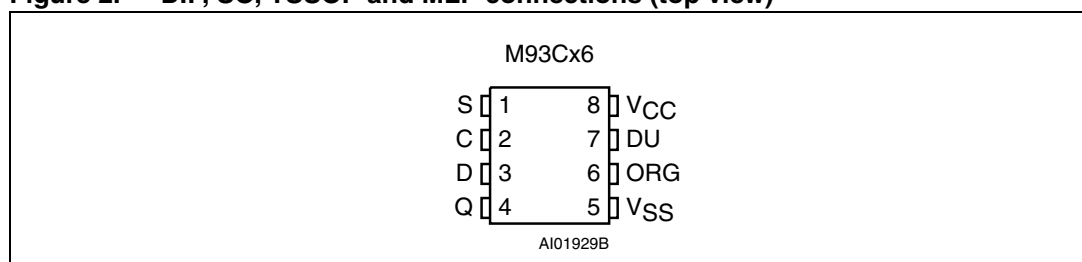
| Instruction | Description                     | Data         |
|-------------|---------------------------------|--------------|
| READ        | Read Data from Memory           | Byte or Word |
| WRITE       | Write Data to Memory            | Byte or Word |
| WEN         | Write Enable                    |              |
| WDS         | Write Disable                   |              |
| ERASE       | Erase Byte or Word              | Byte or Word |
| ERAL        | Erase All Memory                |              |
| WRAL        | Write All Memory with same Data |              |

A Read Data from Memory (READ) instruction loads the address of the first byte or word to be read in an internal address register. The data at this address is then clocked out serially. The address register is automatically incremented after the data is output and, if Chip Select Input (S) is held High, the M93Cx6 can output a sequential stream of data bytes or words. In this way, the memory can be read as a data stream from eight to 16384 bits long (in the case of the M93C86), or continuously (the address counter automatically rolls over to 00h when the highest address is reached).

Programming is internally self-timed (the external clock signal on Serial Clock (C) may be stopped or left running after the start of a Write cycle) and does not require an Erase cycle prior to the Write instruction. The Write instruction writes 8 or 16 bits at a time into one of the byte or word locations of the M93Cx6. After the start of the programming cycle, a Busy/Ready signal is available on Serial Data Output (Q) when Chip Select Input (S) is driven High.

An internal Power-on Data Protection mechanism in the M93Cx6 inhibits the device when the supply is too low.

**Figure 2. DIP, SO, TSSOP and MLP connections (top view)**



1. See [Section 12: Package mechanical data](#) for package dimensions, and how to identify pin-1.
2. DU = Don't Use. The DU (do not use) pin does not contribute to the normal operation of the device. It is reserved for use by STMicroelectronics during test sequences. The pin may be left unconnected or may be connected to V<sub>CC</sub> or V<sub>SS</sub>.

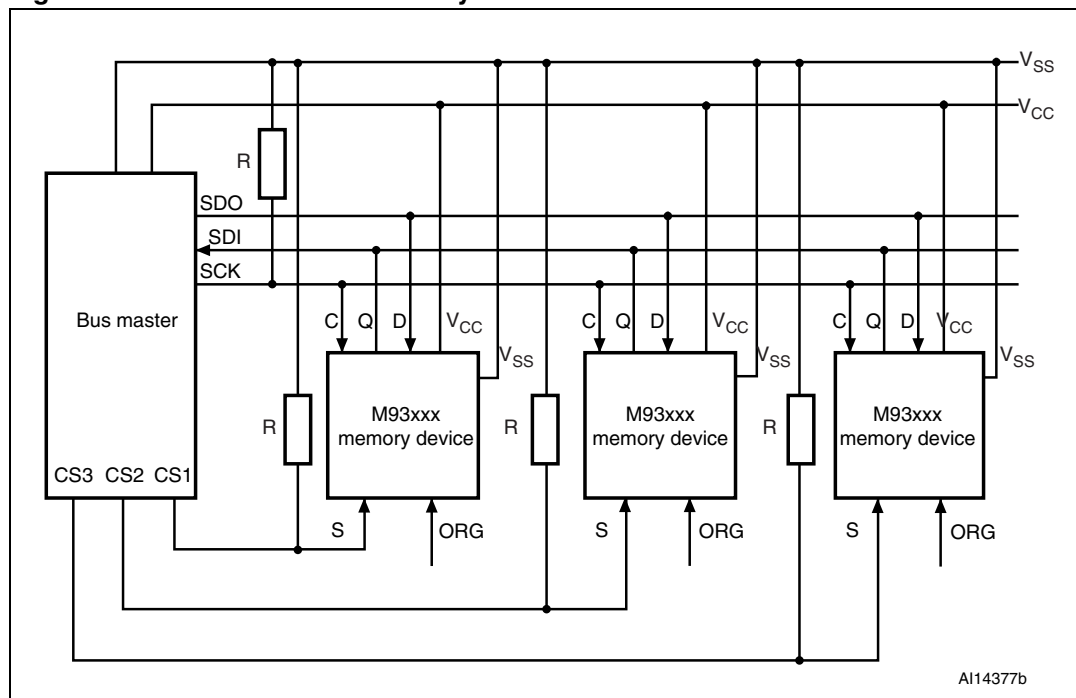
## 2 Connecting to the serial bus

*Figure 3* shows an example of three memory devices connected to an MCU, on a serial bus. Only one device is selected at a time, so only one device drives the Serial Data output (Q) line at a time, the other devices are high impedance.

The pull-down resistor R (represented in *Figure 3*) ensures that no device is selected if the bus master leaves the S line in the high impedance state.

In applications where the bus master may be in a state where all inputs/outputs are high impedance at the same time (for example, if the bus master is reset during the transmission of an instruction), the clock line (C) must be connected to an external pull-down resistor so that, if all inputs/outputs become high impedance, the C line is pulled low (while the S line is pulled low): this ensures that C does not become high at the same time as S goes low, and so, that the  $t_{SLCH}$  requirement is met. The typical value of R is 100 k $\Omega$ .

**Figure 3. Bus master and memory devices on the serial bus**



## 3 Operating features

### 3.1 Supply voltage ( $V_{CC}$ )

#### 3.1.1 Operating supply voltage ( $V_{CC}$ )

Prior to selecting the memory and issuing instructions to it, a valid and stable  $V_{CC}$  voltage within the specified [ $V_{CC}(\min)$ ,  $V_{CC}(\max)$ ] range must be applied. In order to secure a stable DC supply voltage, it is recommended to decouple the  $V_{CC}$  line with a suitable capacitor (usually of the order of 10 nF to 100 nF) close to the  $V_{CC}/V_{SS}$  package pins.

This voltage must remain stable and valid until the end of the transmission of the instruction and, for a Write instruction, until the completion of the internal write cycle ( $t_W$ ).

#### 3.1.2 Power-up conditions

When the power supply is turned on,  $V_{CC}$  rises from  $V_{SS}$  to  $V_{CC}$ . During this time, the Chip Select (S) line is not allowed to float and should be driven to  $V_{SS}$ , it is therefore recommended to connect the S line to  $V_{SS}$  via a suitable pull-down resistor.

The  $V_{CC}$  rise time must not vary faster than 1 V/ $\mu$ s.

#### 3.1.3 Power-up and device reset

In order to prevent inadvertent Write operations during power-up, a power on reset (POR) circuit is included. At power-up (continuous rise of  $V_{CC}$ ), the device does not respond to any instruction until  $V_{CC}$  has reached the power on reset threshold voltage (this threshold is lower than the minimum  $V_{CC}$  operating voltage defined in [Table 9: Operating conditions \(M93Cx6\)](#), [Table 10: Operating conditions \(M93Cx6-W\)](#) and [Table 11: Operating conditions \(M93Cx6-R\)](#)).

When  $V_{CC}$  passes the POR threshold, the device is reset and is in the following state:

- Standby Power mode
- deselected (assuming that there is a pull-down resistor on the S line)

#### 3.1.4 Power-down

At power-down (continuous decrease in  $V_{CC}$ ), as soon as  $V_{CC}$  drops from the normal operating voltage to below the power on reset threshold voltage, the device stops responding to any instruction sent to it.

During power-down, the device must be deselected and in the Standby Power mode (that is, there should be no internal Write cycle in progress).



## 4 Memory organization

The M93Cx6 memory is organized either as bytes (x8) or as words (x16). If Organization Select (ORG) is left unconnected (or connected to  $V_{CC}$ ) the x16 organization is selected; when Organization Select (ORG) is connected to Ground ( $V_{SS}$ ) the x8 organization is selected. When the M93Cx6 is in Standby mode, Organization Select (ORG) should be set either to  $V_{SS}$  or  $V_{CC}$  for minimum power consumption. Any voltage between  $V_{SS}$  and  $V_{CC}$  applied to Organization Select (ORG) may increase the Standby current.

## 5 Instructions

The instruction set of the M93Cx6 devices contains seven instructions, as summarized in [Table 5](#) to [Table 7](#). Each instruction consists of the following parts, as shown in [Figure 4: READ, WRITE, WEN, WDS sequences](#):

- Each instruction is preceded by a rising edge on Chip Select Input (S) with Serial Clock (C) being held low.
- A start bit, which is the first '1' read on Serial Data Input (D) during the rising edge of Serial Clock (C).
- Two op-code bits, read on Serial Data Input (D) during the rising edge of Serial Clock (C). (Some instructions also use the first two bits of the address to define the op-code).
- The address bits of the byte or word that is to be accessed. For the M93C46, the address is made up of 6 bits for the x16 organization or 7 bits for the x8 organization (see [Table 5](#)). For the M93C56 and M93C66, the address is made up of 8 bits for the x16 organization or 9 bits for the x8 organization (see [Table 6](#)). For the M93C76 and M93C86, the address is made up of 10 bits for the x16 organization or 11 bits for the x8 organization (see [Table 7](#)).

The M93Cx6 devices are fabricated in CMOS technology and are therefore able to run as slow as 0 Hz (static input signals) or as fast as the maximum ratings specified in [Table 20: AC characteristics \(M93Cx6, device grade 6 or 3\)](#) to [Table 23: AC characteristics \(M93Cx6-R\)](#).

**Table 5. Instruction set for the M93C46**

| Instruction | Description                     | Start bit | Op-code | x8 origination (ORG = 0) |       |                       | x16 origination (ORG = 1) |        |                       |
|-------------|---------------------------------|-----------|---------|--------------------------|-------|-----------------------|---------------------------|--------|-----------------------|
|             |                                 |           |         | Address (1)              | Data  | Required clock cycles | Address (1)               | Data   | Required clock cycles |
| READ        | Read Data from Memory           | 1         | 10      | A6-A0                    | Q7-Q0 |                       | A5-A0                     | Q15-Q0 |                       |
| WRITE       | Write Data to Memory            | 1         | 01      | A6-A0                    | D7-D0 | 18                    | A5-A0                     | D15-D0 | 25                    |
| WEN         | Write Enable                    | 1         | 00      | 11X<br>XXXX              |       | 10                    | 11 XXXX                   |        | 9                     |
| WDS         | Write Disable                   | 1         | 00      | 00X<br>XXXX              |       | 10                    | 00 XXXX                   |        | 9                     |
| ERASE       | Erase Byte or Word              | 1         | 11      | A6-A0                    |       | 10                    | A5-A0                     |        | 9                     |
| ERAL        | Erase All Memory                | 1         | 00      | 10X<br>XXXX              |       | 10                    | 10 XXXX                   |        | 9                     |
| WRAL        | Write All Memory with same Data | 1         | 00      | 01X<br>XXXX              | D7-D0 | 18                    | 01 XXXX                   | D15-D0 | 25                    |

1. X = Don't Care bit.

**Table 6. Instruction set for the M93C56 and M93C66**

| Instruction | Description                     | Start bit | Op-code | x8 origination (ORG = 0) |       |                       | x16 origination (ORG = 1) |        |                       |
|-------------|---------------------------------|-----------|---------|--------------------------|-------|-----------------------|---------------------------|--------|-----------------------|
|             |                                 |           |         | Address (1) (2)          | Data  | Required clock cycles | Address (1) (3)           | Data   | Required clock cycles |
| READ        | Read Data from Memory           | 1         | 10      | A8-A0                    | Q7-Q0 |                       | A7-A0                     | Q15-Q0 |                       |
| WRITE       | Write Data to Memory            | 1         | 01      | A8-A0                    | D7-D0 | 20                    | A7-A0                     | D15-D0 | 27                    |
| WEN         | Write Enable                    | 1         | 00      | 1 1XXX<br>XXXX           |       | 12                    | 11XX<br>XXXX              |        | 11                    |
| WDS         | Write Disable                   | 1         | 00      | 0 0XXX<br>XXXX           |       | 12                    | 00XX<br>XXXX              |        | 11                    |
| ERASE       | Erase Byte or Word              | 1         | 11      | A8-A0                    |       | 12                    | A7-A0                     |        | 11                    |
| ERAL        | Erase All Memory                | 1         | 00      | 1 0XXX<br>XXXX           |       | 12                    | 10XX<br>XXXX              |        | 11                    |
| WRAL        | Write All Memory with same Data | 1         | 00      | 0 1XXX<br>XXXX           | D7-D0 | 20                    | 01XX<br>XXXX              | D15-D0 | 27                    |

1. X = Don't Care bit.

2. Address bit A8 is not decoded by the M93C56.

3. Address bit A7 is not decoded by the M93C56.

**Table 7. Instruction set for the M93C76 and M93C86**

| Instruction | Description                     | Start bit | Op-code | x8 Origination (ORG = 0)        |       |                       | x16 Origination (ORG = 1) |        |                       |
|-------------|---------------------------------|-----------|---------|---------------------------------|-------|-----------------------|---------------------------|--------|-----------------------|
|             |                                 |           |         | Address <sup>(1)</sup> ,<br>(2) | Data  | Required clock cycles | Address (1) (3)           | Data   | Required clock cycles |
| READ        | Read Data from Memory           | 1         | 10      | A10-A0                          | Q7-Q0 |                       | A9-A0                     | Q15-Q0 |                       |
| WRITE       | Write Data to Memory            | 1         | 01      | A10-A0                          | D7-D0 | 22                    | A9-A0                     | D15-D0 | 29                    |
| WEN         | Write Enable                    | 1         | 00      | 11X XXXX<br>XXXX                |       | 14                    | 11 XXXX<br>XXXX           |        | 13                    |
| WDS         | Write Disable                   | 1         | 00      | 00X XXXX<br>XXXX                |       | 14                    | 00 XXXX<br>XXXX           |        | 13                    |
| ERASE       | Erase Byte or Word              | 1         | 11      | A10-A0                          |       | 14                    | A9-A0                     |        | 13                    |
| ERAL        | Erase All Memory                | 1         | 00      | 10X XXXX<br>XXXX                |       | 14                    | 10 XXXX<br>XXXX           |        | 13                    |
| WRAL        | Write All Memory with same Data | 1         | 00      | 01X XXXX<br>XXXX                | D7-D0 | 22                    | 01 XXXX<br>XXXX           | D15-D0 | 29                    |

1. X = Don't Care bit.

2. Address bit A10 is not decoded by the M93C76.

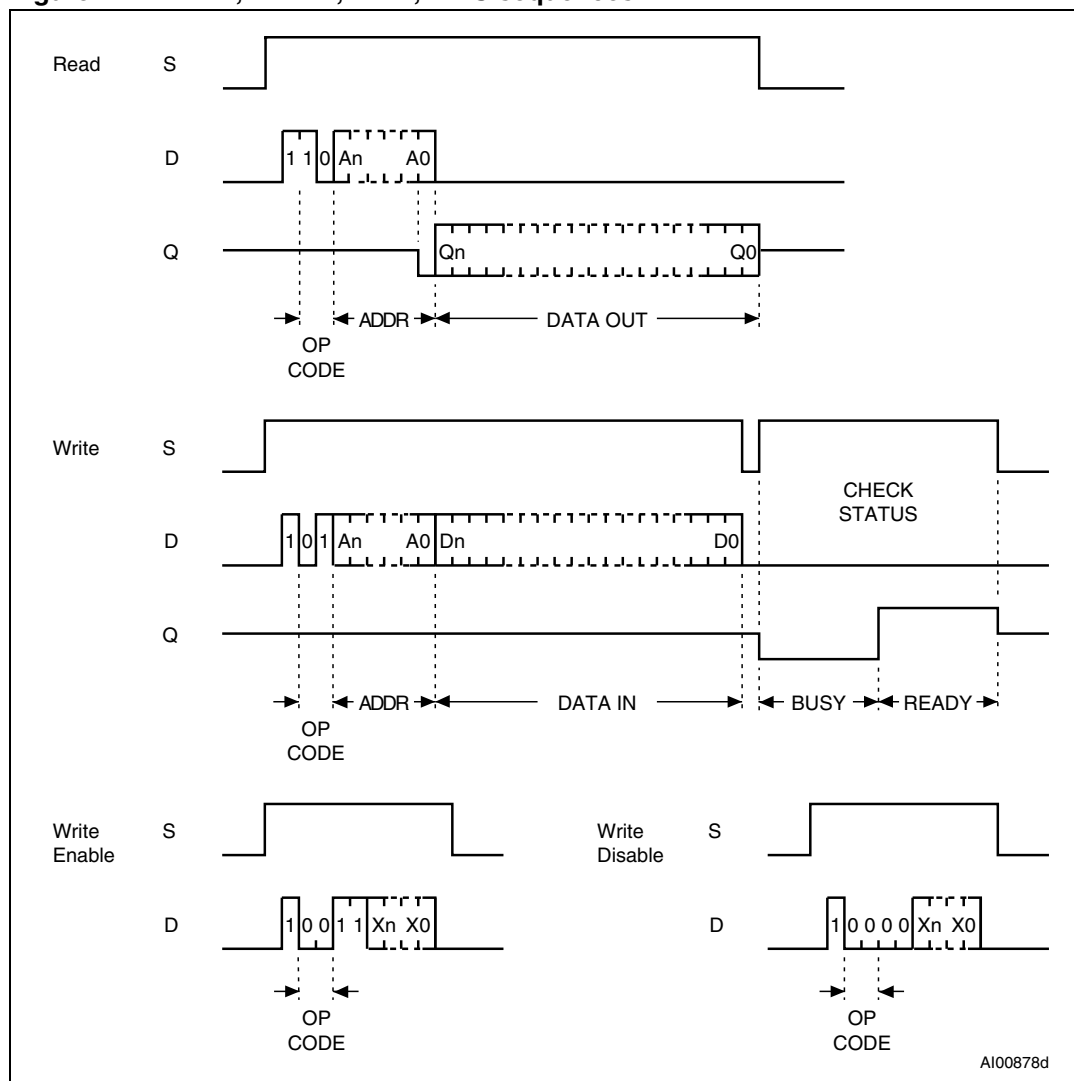
3. Address bit A9 is not decoded by the M93C76.

## 5.1 Read Data from Memory

The Read Data from Memory (READ) instruction outputs data on Serial Data Output (Q). When the instruction is received, the op-code and address are decoded, and the data from the memory is transferred to an output shift register. A dummy 0 bit is output first, followed by the 8-bit byte or 16-bit word, with the most significant bit first. Output data changes are triggered by the rising edge of Serial Clock (C). The M93Cx6 automatically increments the internal address register and clocks out the next byte (or word) as long as the Chip Select Input (S) is held High. In this case, the dummy 0 bit is *not* output between bytes (or words) and a continuous stream of data can be read.

## 5.2 Write Enable and Write Disable

The Write Enable (WEN) instruction enables the future execution of erase or write instructions, and the Write Disable (WDS) instruction disables it. When power is first applied, the M93Cx6 initializes itself so that erase and write instructions are disabled. After an Write Enable (WEN) instruction has been executed, erasing and writing remains enabled until an Write Disable (WDS) instruction is executed, or until  $V_{CC}$  falls below the power-on reset threshold voltage. To protect the memory contents from accidental corruption, it is advisable to issue the Write Disable (WDS) instruction after every write cycle. The Read Data from Memory (READ) instruction is not affected by the Write Enable (WEN) or Write Disable (WDS) instructions.

**Figure 4. READ, WRITE, WEN, WDS sequences**

1. For the meanings of  $A_n$ ,  $X_n$ ,  $Q_n$  and  $D_n$ , see [Table 5](#), [Table 6](#) and [Table 7](#).

### 5.3 Erase Byte or Word

The Erase Byte or Word (ERASE) instruction sets the bits of the addressed memory byte (or word) to 1. Once the address has been correctly decoded, the falling edge of the Chip Select Input (S) starts the self-timed Erase cycle. The completion of the cycle can be detected by monitoring the **READY/BUSY** line, as described in [Section 6: READY/BUSY status](#).

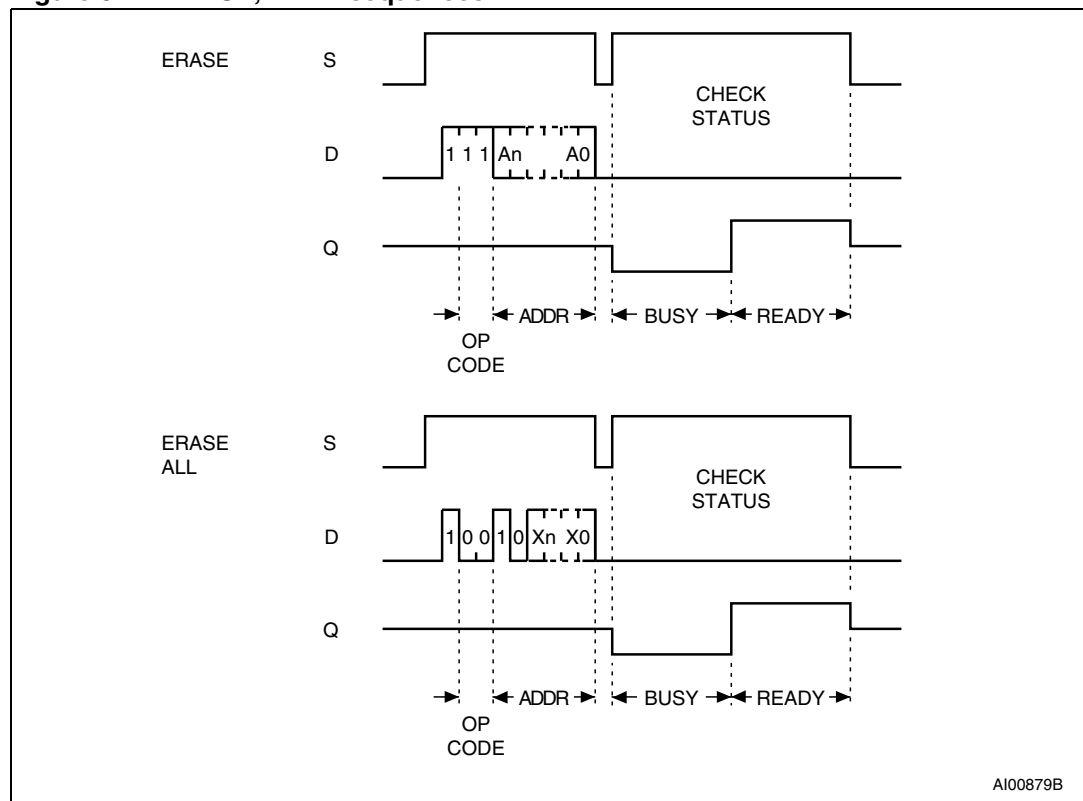
## 5.4 Write

For the Write Data to Memory (WRITE) instruction, 8 or 16 data bits follow the op-code and address bits. These form the byte or word that is to be written. As with the other bits, Serial Data Input (D) is sampled on the rising edge of Serial Clock (C).

After the last data bit has been sampled, the Chip Select Input (S) must be taken low before the next rising edge of Serial Clock (C). If Chip Select Input (S) is brought low before or after this specific time frame, the self-timed programming cycle will not be started, and the addressed location will not be programmed. The completion of the cycle can be detected by monitoring the READY/BUSY line, as described later in this document.

Once the Write cycle has been started, it is internally self-timed (the external clock signal on Serial Clock (C) may be stopped or left running after the start of a Write cycle). The cycle is automatically preceded by an Erase cycle, so it is unnecessary to execute an explicit erase instruction before a Write Data to Memory (WRITE) instruction.

**Figure 5. ERASE, ERAL sequences**



1. For the meanings of An and Xn, please see [Table 5](#), [Table 6](#) and [Table 7](#).

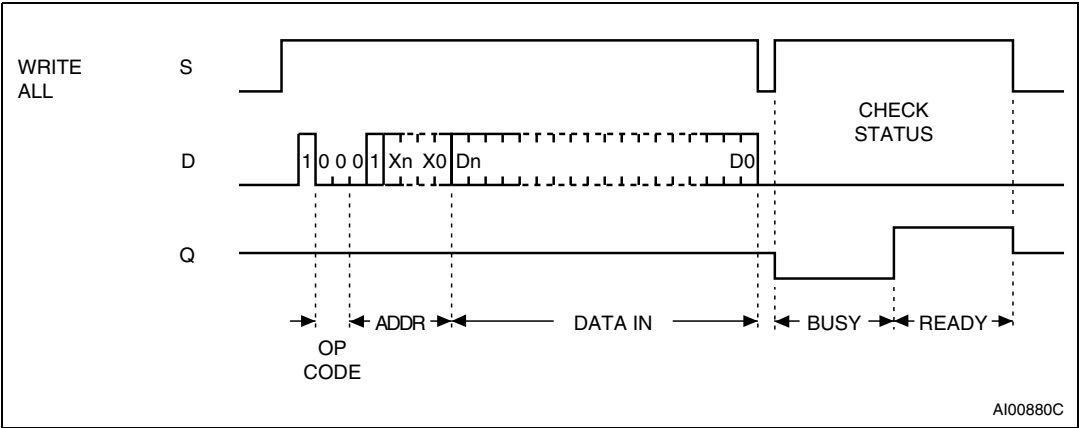
## 5.5 Erase All

The Erase All Memory (ERAL) instruction erases the whole memory (all memory bits are set to 1). The format of the instruction requires that a dummy address be provided. The Erase cycle is conducted in the same way as the Erase instruction (ERASE). The completion of the cycle can be detected by monitoring the READY/BUSY line, as described in [Section 6: READY/BUSY status](#).

### 5.6 Write All

As with the Erase All Memory (ERAL) instruction, the format of the Write All Memory with same Data (WRAL) instruction requires that a dummy address be provided. As with the Write Data to Memory (WRITE) instruction, the format of the Write All Memory with same Data (WRAL) instruction requires that an 8-bit data byte, or 16-bit data word, be provided. This value is written to all the addresses of the memory device. The completion of the cycle can be detected by monitoring the READY/BUSY line, as described next.

Figure 6. WRAL sequence



1. For the meanings of X<sub>n</sub> and D<sub>n</sub>, please see [Table 5](#), [Table 6](#) and [Table 7](#).

## 6 **READY/ $\overline{\text{BUSY}}$ status**

While the Write or Erase cycle is underway, for a WRITE, ERASE, WRAL or ERAL instruction, the Busy signal ( $Q=0$ ) is returned whenever Chip Select input (S) is driven high. (Please note, though, that there is an initial delay, of  $t_{\text{SLSH}}$ , before this status information becomes available). In this state, the M93Cx6 ignores any data on the bus. When the Write cycle is completed, and Chip Select Input (S) is driven high, the Ready signal ( $Q=1$ ) indicates that the M93Cx6 is ready to receive the next instruction. Serial Data Output (Q) remains set to 1 until the Chip Select Input (S) is brought low or until a new start bit is decoded.

## 7 **Initial delivery state**

The device is delivered with all bits in the memory array set to 1 (each byte contains FFh).

## 8 **Common I/O operation**

Serial Data Output (Q) and Serial Data Input (D) can be connected together, through a current limiting resistor, to form a common, single-wire data bus. Some precautions must be taken when operating the memory in this way, mostly to prevent a short circuit current from flowing when the last address bit (A0) clashes with the first data bit on Serial Data Output (Q). Please see the application note *AN394* for details.



## 9 Clock pulse counter

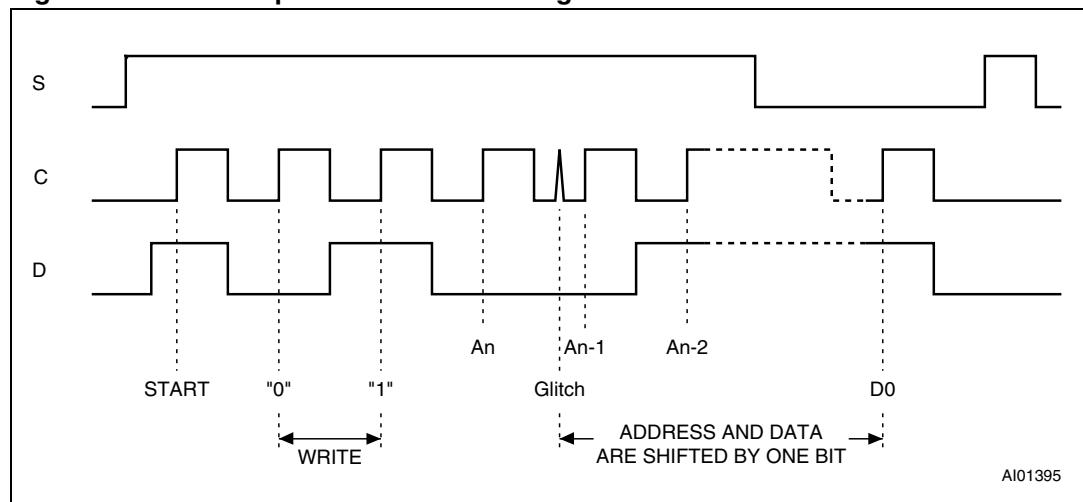
In a noisy environment, the number of pulses received on Serial Clock (C) may be greater than the number delivered by the master (the microcontroller). This can lead to a misalignment of the instruction of one or more bits (as shown in [Figure 7](#)) and may lead to the writing of erroneous data at an erroneous address.

To avoid this problem, the M93Cx6 has an on-chip counter that counts the clock pulses from the start bit until the falling edge of the Chip Select Input (S). If the number of clock pulses received is not the number expected, the WRITE, ERASE, ERAL or WRAL instruction is aborted, and the contents of the memory are not modified.

The number of clock cycles expected for each instruction, and for each member of the M93Cx6 family, are summarized in [Table 5: Instruction set for the M93C46](#) to [Table 7: Instruction set for the M93C76 and M93C86](#). For example, a Write Data to Memory (WRITE) instruction on the M93C56 (or M93C66) expects 20 clock cycles (for the x8 organization) from the start bit to the falling edge of Chip Select Input (S). That is:

- 1 Start bit
- + 2 Op-code bits
- + 9 Address bits
- + 8 Data bits

**Figure 7. Write sequence with one clock glitch**



## 10 Maximum rating

Stressing the device above the rating listed in the absolute maximum ratings table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics SURE Program and other relevant quality documents.

**Table 8. Absolute maximum ratings**

| Symbol     | Parameter                                                         |                | Min.                    | Max.               | Unit |
|------------|-------------------------------------------------------------------|----------------|-------------------------|--------------------|------|
| $T_B$      | Ambient operating temperature                                     |                | -40                     | 130                | °C   |
| $T_{STG}$  | Storage temperature                                               |                | -65                     | 150                | °C   |
| $T_{LEAD}$ | Lead temperature during soldering                                 | PDIP           |                         | 260 <sup>(1)</sup> |      |
|            |                                                                   | other packages | See note <sup>(2)</sup> |                    | °C   |
| $V_{OUT}$  | Output range ( $Q = V_{OH}$ or Hi-Z)                              |                | -0.50                   | $V_{CC}+0.5$       | V    |
| $V_{IN}$   | Input range                                                       |                | -0.50                   | $V_{CC}+1$         | V    |
| $V_{CC}$   | Supply voltage                                                    |                | -0.50                   | 6.5                | V    |
| $V_{ESD}$  | Electrostatic discharge voltage (human body model) <sup>(3)</sup> |                |                         | 4000               | V    |

1.  $T_{LEAD}$  max must *not* be applied for more than 10 s.
2. Compliant with JEDEC Std J-STD-020 (for small body, Sn-Pb or Pb assembly), the ST ECOPACK® 7191395 specification, and the European directive on Restrictions on Hazardous Substances (RoHS) 2002/95/EU.
3. Positive and negative pulses applied on pin pairs, according to the AEC-Q100-002 (compliant with JEDEC Std JESD22-A114, C1 = 100pF, R1 = 1500Ω, R2 = 500Ω).

# 11 DC and AC parameters

This section summarizes the operating and measurement conditions, and the dc and ac characteristics of the device. The parameters in the dc and ac characteristic tables that follow are derived from tests performed under the measurement conditions summarized in the relevant tables. Designers should check that the operating conditions in their circuit match the measurement conditions when relying on the quoted parameters.

**Table 9. Operating conditions (M93Cx6)**

| Symbol   | Parameter                                      | Min. | Max. | Unit |
|----------|------------------------------------------------|------|------|------|
| $V_{CC}$ | Supply voltage                                 | 4.5  | 5.5  | V    |
| $T_A$    | Ambient operating temperature (device grade 6) | -40  | 85   | °C   |
|          | Ambient operating temperature (device grade 3) | -40  | 125  | °C   |

**Table 10. Operating conditions (M93Cx6-W)**

| Symbol   | Parameter                                      | Min. | Max. | Unit |
|----------|------------------------------------------------|------|------|------|
| $V_{CC}$ | Supply voltage                                 | 2.5  | 5.5  | V    |
| $T_A$    | Ambient operating temperature (device grade 6) | -40  | 85   | °C   |
|          | Ambient operating temperature (device grade 3) | -40  | 125  | °C   |

**Table 11. Operating conditions (M93Cx6-R)**

| Symbol   | Parameter                                      | Min. | Max. | Unit |
|----------|------------------------------------------------|------|------|------|
| $V_{CC}$ | Supply voltage                                 | 1.8  | 5.5  | V    |
| $T_A$    | Ambient operating temperature (device grade 6) | -40  | 85   | °C   |

**Table 12. AC measurement conditions (M93Cx6)<sup>(1)</sup>**

| Symbol | Parameter                        | Min.            | Max. | Unit |
|--------|----------------------------------|-----------------|------|------|
| $C_L$  | Load capacitance                 | 100             |      | pF   |
|        | Input rise and fall times        |                 | 50   | ns   |
|        | Input pulse voltages             | 0.4 V to 2.4 V  |      | V    |
|        | Input timing reference voltages  | 1.0 V and 2.0 V |      | V    |
|        | Output timing reference voltages | 0.8 V and 2.0 V |      | V    |

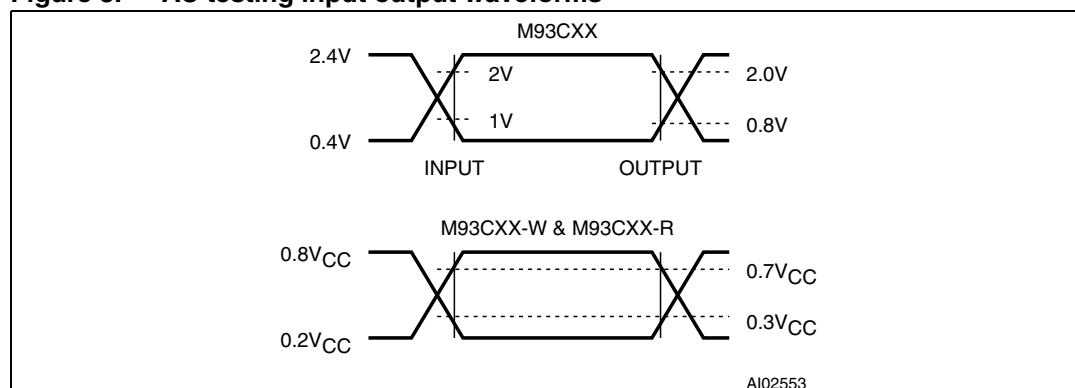
1. Output Hi-Z is defined as the point where data out is no longer driven.

**Table 13. AC measurement conditions (M93Cx6-W and M93Cx6-R)<sup>(1)</sup>**

| Symbol         | Parameter                        | Min.                                     | Max. | Unit |
|----------------|----------------------------------|------------------------------------------|------|------|
| C <sub>L</sub> | Load capacitance                 | 100                                      |      | pF   |
|                | Input rise and fall times        |                                          | 50   | ns   |
|                | Input pulse voltages             | 0.2V <sub>CC</sub> to 0.8V <sub>CC</sub> |      | V    |
|                | Input timing reference voltages  | 0.3V <sub>CC</sub> to 0.7V <sub>CC</sub> |      | V    |
|                | Output timing reference voltages | 0.3V <sub>CC</sub> to 0.7V <sub>CC</sub> |      | V    |

1. Output Hi-Z is defined as the point where data out is no longer driven.

**Figure 8. AC testing input output waveforms**



**Table 14. Capacitance<sup>(1)</sup>**

| Symbol           | Parameter          | Test condition        | Min | Max | Unit |
|------------------|--------------------|-----------------------|-----|-----|------|
| C <sub>OUT</sub> | Output capacitance | V <sub>OUT</sub> = 0V |     | 5   | pF   |
| C <sub>IN</sub>  | Input capacitance  | V <sub>IN</sub> = 0V  |     | 5   | pF   |

1. Sampled only, not 100% tested, at  $T_A = 25\text{ }^{\circ}\text{C}$  and a frequency of 1 MHz.

**Table 15. DC characteristics (M93Cx6, device grade 6)**

| Symbol         | Parameter                | Test condition                                                                                                      | Min.        | Max.         | Unit    |
|----------------|--------------------------|---------------------------------------------------------------------------------------------------------------------|-------------|--------------|---------|
| $I_{LI}$       | Input leakage current    | $0V \leq V_{IN} \leq V_{CC}$                                                                                        |             | $\pm 2.5$    | $\mu A$ |
| $I_{LO}$       | Output leakage current   | $0V \leq V_{OUT} \leq V_{CC}$ , Q in Hi-Z                                                                           |             | $\pm 2.5$    | $\mu A$ |
| $I_{CC}$       | Supply current           | $V_{CC} = 5V$ , $S = V_{IH}$ , $f = 2MHz$ ,<br>Q = open                                                             |             | 2            | mA      |
| $I_{CC1}$      | Supply current (Standby) | $V_{CC} = 5V$ , $S = V_{SS}$ , $C = V_{SS}$ ,<br>ORG = $V_{SS}$ or $V_{CC}$ ,<br>pin7 = $V_{CC}$ , $V_{SS}$ or Hi-Z |             | 15           | $\mu A$ |
| $V_{IL}^{(1)}$ | Input low voltage        | $V_{CC} = 5V \pm 10\%$                                                                                              | -0.45       | 0.8          | V       |
| $V_{IH}^{(1)}$ | Input high voltage       | $V_{CC} = 5V \pm 10\%$                                                                                              | 2           | $V_{CC} + 1$ | V       |
| $V_{OL}^{(1)}$ | Output low voltage       | $V_{CC} = 5V$ , $I_{OL} = 2.1mA$                                                                                    |             | 0.4          | V       |
| $V_{OH}^{(1)}$ | Output high voltage      | $V_{CC} = 5V$ , $I_{OH} = -400\mu A$                                                                                | $0.8V_{CC}$ |              | V       |

1. Please note that the input and output levels defined in this table are compatible with TTL logic levels and are NOT fully compatible with CMOS levels (as defined in [Table 17](#))

**Table 16. DC characteristics (M93Cx6, device grade 3)**

| Symbol         | Parameter                | Test condition                                                                                                      | Min.         | Max.         | Unit    |
|----------------|--------------------------|---------------------------------------------------------------------------------------------------------------------|--------------|--------------|---------|
| $I_{LI}$       | Input leakage current    | $0V \leq V_{IN} \leq V_{CC}$                                                                                        |              | $\pm 2.5$    | $\mu A$ |
| $I_{LO}$       | Output leakage current   | $0V \leq V_{OUT} \leq V_{CC}$ , Q in Hi-Z                                                                           |              | $\pm 2.5$    | $\mu A$ |
| $I_{CC}$       | Supply current           | $V_{CC} = 5V$ , $S = V_{IH}$ , $f = 2 MHz$ ,<br>Q = open                                                            |              | 2            | mA      |
| $I_{CC1}$      | Supply current (Standby) | $V_{CC} = 5V$ , $S = V_{SS}$ , $C = V_{SS}$ ,<br>ORG = $V_{SS}$ or $V_{CC}$ ,<br>pin7 = $V_{CC}$ , $V_{SS}$ or Hi-Z |              | 15           | $\mu A$ |
| $V_{IL}^{(1)}$ | Input low voltage        | $V_{CC} = 5V \pm 10\%$                                                                                              | -0.45        | 0.8          | V       |
| $V_{IH}^{(1)}$ | Input high voltage       | $V_{CC} = 5V \pm 10\%$                                                                                              | 2            | $V_{CC} + 1$ | V       |
| $V_{OL}^{(1)}$ | Output low voltage       | $V_{CC} = 5V$ , $I_{OL} = 2.1 mA$                                                                                   |              | 0.4          | V       |
| $V_{OH}^{(1)}$ | Output high voltage      | $V_{CC} = 5V$ , $I_{OH} = -400 \mu A$                                                                               | $0.8 V_{CC}$ |              | V       |

1. Please note that the input and output levels defined in this table are compatible with TTL logic levels and are NOT fully compatible with CMOS levels (as defined in [Table 17](#))

**Table 17. DC characteristics (M93Cx6-W, device grade 6)**

| Symbol    | Parameter                    | Test condition                                                                                                        | Min.           | Max.         | Unit    |
|-----------|------------------------------|-----------------------------------------------------------------------------------------------------------------------|----------------|--------------|---------|
| $I_{LI}$  | Input leakage current        | $0V \leq V_{IN} \leq V_{CC}$                                                                                          |                | $\pm 2.5$    | $\mu A$ |
| $I_{LO}$  | Output leakage current       | $0V \leq V_{OUT} \leq V_{CC}$ , Q in Hi-Z                                                                             |                | $\pm 2.5$    | $\mu A$ |
| $I_{CC}$  | Supply current (CMOS inputs) | $V_{CC} = 5V$ , $S = V_{IH}$ , $f = 2 MHz$ ,<br>Q = open                                                              |                | 2            | mA      |
|           |                              | $V_{CC} = 2.5V$ , $S = V_{IH}$ , $f = 2 MHz$ ,<br>Q = open                                                            |                | 1            | mA      |
| $I_{CC1}$ | Supply current (Standby)     | $V_{CC} = 2.5V$ , $S = V_{SS}$ , $C = V_{SS}$ ,<br>ORG = $V_{SS}$ or $V_{CC}$ ,<br>pin7 = $V_{CC}$ , $V_{SS}$ or Hi-Z |                | 5            | $\mu A$ |
| $V_{IL}$  | Input low voltage (D, C, S)  |                                                                                                                       | -0.45          | $0.2 V_{CC}$ | V       |
| $V_{IH}$  | Input high voltage (D, C, S) |                                                                                                                       | $0.7 V_{CC}$   | $V_{CC} + 1$ | V       |
| $V_{OL}$  | Output low voltage (Q)       | $V_{CC} = 5V$ , $I_{OL} = 2.1 mA$                                                                                     |                | 0.4          | V       |
|           |                              | $V_{CC} = 2.5V$ , $I_{OL} = 100 \mu A$                                                                                |                | 0.2          | V       |
| $V_{OH}$  | Output high voltage (Q)      | $V_{CC} = 5V$ , $I_{OH} = -400 \mu A$                                                                                 | $0.8 V_{CC}$   |              | V       |
|           |                              | $V_{CC} = 2.5V$ , $I_{OH} = -100 \mu A$                                                                               | $V_{CC} - 0.2$ |              | V       |

**Table 18. DC characteristics (M93Cx6-W, device grade 3)**

| Symbol    | Parameter                    | Test condition                                                                                                        | Min. <sup>(1)</sup> | Max. <sup>(1)</sup> | Unit    |
|-----------|------------------------------|-----------------------------------------------------------------------------------------------------------------------|---------------------|---------------------|---------|
| $I_{LI}$  | Input leakage current        | $0V \leq V_{IN} \leq V_{CC}$                                                                                          |                     | $\pm 2.5$           | $\mu A$ |
| $I_{LO}$  | Output leakage current       | $0V \leq V_{OUT} \leq V_{CC}$ , Q in Hi-Z                                                                             |                     | $\pm 2.5$           | $\mu A$ |
| $I_{CC}$  | Supply current (CMOS inputs) | $V_{CC} = 5V$ , $S = V_{IH}$ , $f = 2\text{ MHz}$ ,<br>Q = open                                                       |                     | 2                   | mA      |
|           |                              | $V_{CC} = 2.5V$ , $S = V_{IH}$ , $f = 2\text{ MHz}$ ,<br>Q = open                                                     |                     | 1                   | mA      |
| $I_{CC1}$ | Supply current (Standby)     | $V_{CC} = 2.5V$ , $S = V_{SS}$ , $C = V_{SS}$ ,<br>ORG = $V_{SS}$ or $V_{CC}$ ,<br>pin7 = $V_{CC}$ , $V_{SS}$ or Hi-Z |                     | 5                   | $\mu A$ |
| $V_{IL}$  | Input low voltage (D, C, S)  |                                                                                                                       | -0.45               | $0.2 V_{CC}$        | V       |
| $V_{IH}$  | Input high voltage (D, C, S) |                                                                                                                       | $0.7 V_{CC}$        | $V_{CC} + 1$        | V       |
| $V_{OL}$  | Output low voltage (Q)       | $V_{CC} = 5V$ , $I_{OL} = 2.1\text{ mA}$                                                                              |                     | 0.4                 | V       |
|           |                              | $V_{CC} = 2.5V$ , $I_{OL} = 100\text{ }\mu A$                                                                         |                     | 0.2                 | V       |
| $V_{OH}$  | Output high voltage (Q)      | $V_{CC} = 5V$ , $I_{OH} = -400\text{ }\mu A$                                                                          | $0.8 V_{CC}$        |                     | V       |
|           |                              | $V_{CC} = 2.5V$ , $I_{OH} = -100\text{ }\mu A$                                                                        | $V_{CC} - 0.2$      |                     | V       |

1. New product: identified by Process Identification letter W or G or S.

**Table 19. DC characteristics (M93Cx6-R)**

| Symbol    | Parameter                    | Test condition                                                                                                        | Min. <sup>(1)</sup> | Max. <sup>(1)</sup> | Unit    |
|-----------|------------------------------|-----------------------------------------------------------------------------------------------------------------------|---------------------|---------------------|---------|
| $I_{LI}$  | Input leakage current        | $0V \leq V_{IN} \leq V_{CC}$                                                                                          |                     | $\pm 2.5$           | $\mu A$ |
| $I_{LO}$  | Output leakage current       | $0V \leq V_{OUT} \leq V_{CC}$ , Q in Hi-Z                                                                             |                     | $\pm 2.5$           | $\mu A$ |
| $I_{CC}$  | Supply current (CMOS inputs) | $V_{CC} = 5V$ , $S = V_{IH}$ , $f = 2\text{ MHz}$ ,<br>Q = open                                                       |                     | 2                   | mA      |
|           |                              | $V_{CC} = 1.8V$ , $S = V_{IH}$ , $f = 1\text{ MHz}$ ,<br>Q = open                                                     |                     | 1                   | mA      |
| $I_{CC1}$ | Supply current (Standby)     | $V_{CC} = 1.8V$ , $S = V_{SS}$ , $C = V_{SS}$ ,<br>ORG = $V_{SS}$ or $V_{CC}$ ,<br>pin7 = $V_{CC}$ , $V_{SS}$ or Hi-Z |                     | 2                   | $\mu A$ |
| $V_{IL}$  | Input low voltage (D, C, S)  |                                                                                                                       | -0.45               | $0.2 V_{CC}$        | V       |
| $V_{IH}$  | Input high voltage (D, C, S) |                                                                                                                       | $0.8 V_{CC}$        | $V_{CC} + 1$        | V       |
| $V_{OL}$  | Output low voltage (Q)       | $V_{CC} = 1.8V$ , $I_{OL} = 100\text{ }\mu A$                                                                         |                     | 0.2                 | V       |
| $V_{OH}$  | Output high voltage (Q)      | $V_{CC} = 1.8V$ , $I_{OH} = -100\text{ }\mu A$                                                                        | $V_{CC} - 0.2$      |                     | V       |

1. This product is under development. For more information, please contact your nearest ST sales office.

**Table 20. AC characteristics (M93Cx6, device grade 6 or 3)**

| Test conditions specified in <a href="#">Table 12</a> and <a href="#">Table 9</a> |           |                                                  |      |      |      |
|-----------------------------------------------------------------------------------|-----------|--------------------------------------------------|------|------|------|
| Symbol                                                                            | Alt.      | Parameter                                        | Min. | Max. | Unit |
| $f_C$                                                                             | $f_{SK}$  | Clock frequency                                  | D.C. | 2    | MHz  |
| $t_{SLCH}$                                                                        |           | Chip Select low to Clock high                    | 50   |      | ns   |
| $t_{SHCH}$                                                                        | $t_{CSS}$ | Chip Select setup time<br>M93C46, M93C56, M93C66 | 50   |      | ns   |
|                                                                                   |           | Chip Select setup time<br>M93C76, M93C86         | 50   |      | ns   |
| $t_{SLSH}^{(1)}$                                                                  | $t_{CS}$  | Chip Select low to Chip Select high              | 200  |      | ns   |
| $t_{CHCL}^{(2)}$                                                                  | $t_{SKH}$ | Clock high time                                  | 200  |      | ns   |
| $t_{CLCH}^{(2)}$                                                                  | $t_{SKL}$ | Clock low time                                   | 200  |      | ns   |
| $t_{DVCH}$                                                                        | $t_{DIS}$ | Data in setup time                               | 50   |      | ns   |
| $t_{CHDX}$                                                                        | $t_{DIH}$ | Data in hold time                                | 50   |      | ns   |
| $t_{CLSH}$                                                                        | $t_{SKS}$ | Clock setup time (relative to S)                 | 50   |      | ns   |
| $t_{CLSL}$                                                                        | $t_{CSH}$ | Chip Select hold time                            | 0    |      | ns   |
| $t_{SHQV}$                                                                        | $t_{SV}$  | Chip Select to READY/ $\overline{BUSY}$ status   |      | 200  | ns   |
| $t_{SLQZ}$                                                                        | $t_{DF}$  | Chip Select low to output Hi-Z                   |      | 100  | ns   |
| $t_{CHQL}$                                                                        | $t_{PD0}$ | Delay to output low                              |      | 200  | ns   |
| $t_{CHQV}$                                                                        | $t_{PD1}$ | Delay to output valid                            |      | 200  | ns   |
| $t_W$                                                                             | $t_{WP}$  | Erase or Write cycle time                        |      | 5    | ms   |

1. Chip Select Input (S) must be brought low for a minimum of  $t_{SLSH}$  between consecutive instruction cycles.

2.  $t_{CHCL} + t_{CLCH} \geq 1 / f_C$ .

**Table 21. AC characteristics (M93Cx6-W, device grade 6)**

| Test conditions specified in <a href="#">Table 13</a> and <a href="#">Table 10</a> |           |                                                |      |      |      |
|------------------------------------------------------------------------------------|-----------|------------------------------------------------|------|------|------|
| Symbol                                                                             | Alt.      | Parameter                                      | Min. | Max. | Unit |
| $f_C$                                                                              | $f_{SK}$  | Clock frequency                                | D.C. | 2    | MHz  |
| $t_{SLCH}$                                                                         |           | Chip Select low to Clock high                  | 50   |      | ns   |
| $t_{SHCH}$                                                                         | $t_{CSS}$ | Chip Select setup time                         | 50   |      | ns   |
| $t_{SLSH}^{(1)}$                                                                   | $t_{CS}$  | Chip Select low to Chip Select high            | 200  |      | ns   |
| $t_{CHCL}^{(2)}$                                                                   | $t_{SKH}$ | Clock high time                                | 200  |      | ns   |
| $t_{CLCH}^{(2)}$                                                                   | $t_{SKL}$ | Clock low time                                 | 200  |      | ns   |
| $t_{DVCH}$                                                                         | $t_{DIS}$ | Data in setup time                             | 50   |      | ns   |
| $t_{CHDX}$                                                                         | $t_{DIH}$ | Data in hold time                              | 50   |      | ns   |
| $t_{CLSH}$                                                                         | $t_{SKS}$ | Clock setup time (relative to S)               | 50   |      | ns   |
| $t_{CLSL}$                                                                         | $t_{CSH}$ | Chip Select hold time                          | 0    |      | ns   |
| $t_{SHQV}$                                                                         | $t_{SV}$  | Chip Select to READY/ $\overline{BUSY}$ status |      | 200  | ns   |

**Table 21. AC characteristics (M93Cx6-W, device grade 6) (continued)**

| Test conditions specified in <a href="#">Table 13</a> and <a href="#">Table 10</a> |           |                                |      |      |      |
|------------------------------------------------------------------------------------|-----------|--------------------------------|------|------|------|
| Symbol                                                                             | Alt.      | Parameter                      | Min. | Max. | Unit |
| $t_{SLQZ}$                                                                         | $t_{DF}$  | Chip Select low to output Hi-Z |      | 100  | ns   |
| $t_{CHQL}$                                                                         | $t_{PD0}$ | Delay to output low            |      | 200  | ns   |
| $t_{CHQV}$                                                                         | $t_{PD1}$ | Delay to output valid          |      | 200  | ns   |
| $t_W$                                                                              | $t_{WP}$  | Erase or Write cycle time      |      | 5    | ms   |

1. Chip Select Input (S) must be brought low for a minimum of  $t_{SLSH}$  between consecutive instruction cycles.
2.  $t_{CHCL} + t_{CLCH} \geq 1 / f_C$ .

**Table 22. AC characteristics (M93Cx6-W, device grade 3)**

| Test conditions specified in <a href="#">Table 13</a> and <a href="#">Table 10</a> |           |                                                       |      |      |      |
|------------------------------------------------------------------------------------|-----------|-------------------------------------------------------|------|------|------|
| Symbol                                                                             | Alt.      | Parameter                                             | Min. | Max. | Unit |
| $f_C$                                                                              | $f_{SK}$  | Clock frequency                                       | D.C. | 2    | MHz  |
| $t_{SLCH}$                                                                         |           | Chip Select low to Clock high                         | 50   |      | ns   |
| $t_{SHCH}$                                                                         | $t_{CSS}$ | Chip Select set-up time                               | 50   |      | ns   |
| $t_{SLSH}^{(1)}$                                                                   | $t_{CS}$  | Chip Select low to Chip Select high                   | 200  |      | ns   |
| $t_{CHCL}^{(2)}$                                                                   | $t_{SKH}$ | Clock high time                                       | 200  |      | ns   |
| $t_{CLCH}^{(2)}$                                                                   | $t_{SKL}$ | Clock low time                                        | 200  |      | ns   |
| $t_{DVCH}$                                                                         | $t_{DIS}$ | Data in set-up time                                   | 50   |      | ns   |
| $t_{CHDX}$                                                                         | $t_{DIH}$ | Data in hold time                                     | 50   |      | ns   |
| $t_{CLSH}$                                                                         | $t_{SKS}$ | Clock set-up time (relative to S)                     | 50   |      | ns   |
| $t_{CLSL}$                                                                         | $t_{CSH}$ | Chip Select hold time                                 | 0    |      | ns   |
| $t_{SHQV}$                                                                         | $t_{SV}$  | Chip Select to READY/ $\overline{\text{BUSY}}$ status |      | 200  | ns   |
| $t_{SLQZ}$                                                                         | $t_{DF}$  | Chip Select low to output Hi-Z                        |      | 100  | ns   |
| $t_{CHQL}$                                                                         | $t_{PD0}$ | Delay to output low                                   |      | 200  | ns   |
| $t_{CHQV}$                                                                         | $t_{PD1}$ | Delay to output valid                                 |      | 200  | ns   |
| $t_W$                                                                              | $t_{WP}$  | Erase or Write cycle time                             |      | 5    | ms   |

1. Chip Select Input (S) must be brought low for a minimum of  $t_{SLSH}$  between consecutive instruction cycles.
2.  $t_{CHCL} + t_{CLCH} \geq 1 / f_C$ .



**Table 23. AC characteristics (M93Cx6-R)**

| Test conditions specified in <a href="#">Table 13</a> and <a href="#">Table 11</a> |           |                                                |                     |                     |      |
|------------------------------------------------------------------------------------|-----------|------------------------------------------------|---------------------|---------------------|------|
| Symbol                                                                             | Alt.      | Parameter                                      | Min. <sup>(1)</sup> | Max. <sup>(1)</sup> | Unit |
| $f_C$                                                                              | $f_{SK}$  | Clock frequency                                | D.C.                | 1                   | MHz  |
| $t_{SLCH}$                                                                         |           | Chip Select low to Clock high                  | 250                 |                     | ns   |
| $t_{SHCH}$                                                                         | $t_{CSS}$ | Chip Select setup time                         | 50                  |                     | ns   |
| $t_{SLSH}^{(2)}$                                                                   | $t_{CS}$  | Chip Select low to Chip Select high            | 250                 |                     | ns   |
| $t_{CHCL}^{(3)}$                                                                   | $t_{SKH}$ | Clock high time                                | 250                 |                     | ns   |
| $t_{CLCH}^{(3)}$                                                                   | $t_{SKL}$ | Clock low time                                 | 250                 |                     | ns   |
| $t_{DVCH}$                                                                         | $t_{DIS}$ | Data in setup time                             | 100                 |                     | ns   |
| $t_{CHDX}$                                                                         | $t_{DIH}$ | Data in hold time                              | 100                 |                     | ns   |
| $t_{CLSH}$                                                                         | $t_{SKS}$ | Clock setup time (relative to S)               | 100                 |                     | ns   |
| $t_{CLSL}$                                                                         | $t_{CSH}$ | Chip Select hold time                          | 0                   |                     | ns   |
| $t_{SHQV}$                                                                         | $t_{SV}$  | Chip Select to READY/ $\overline{BUSY}$ status |                     | 400                 | ns   |
| $t_{SLQZ}$                                                                         | $t_{DF}$  | Chip Select low to output Hi-Z                 |                     | 200                 | ns   |
| $t_{CHQL}$                                                                         | $t_{PD0}$ | Delay to output low                            |                     | 400                 | ns   |
| $t_{CHQV}$                                                                         | $t_{PD1}$ | Delay to output valid                          |                     | 400                 | ns   |
| $t_W$                                                                              | $t_{WP}$  | Erase or Write cycle time                      |                     | 10                  | ms   |

1. This product is under development. For more information, please contact your nearest ST sales office.
2. Chip Select Input (S) must be brought low for a minimum of  $t_{SLSH}$  between consecutive instruction cycles.
3.  $t_{CHCL} + t_{CLCH} \geq 1 / f_C$ .

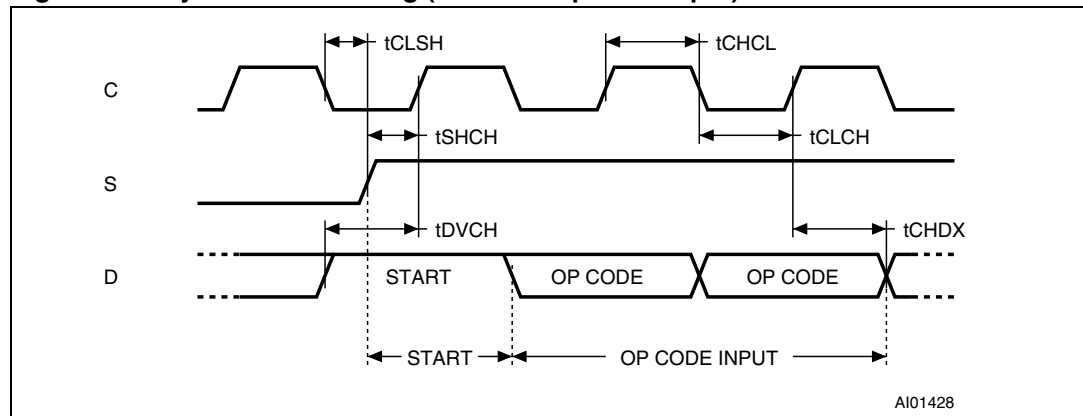
**Figure 9. Synchronous timing (start and op-code input)**

Figure 10. Synchronous timing (Read or Write)

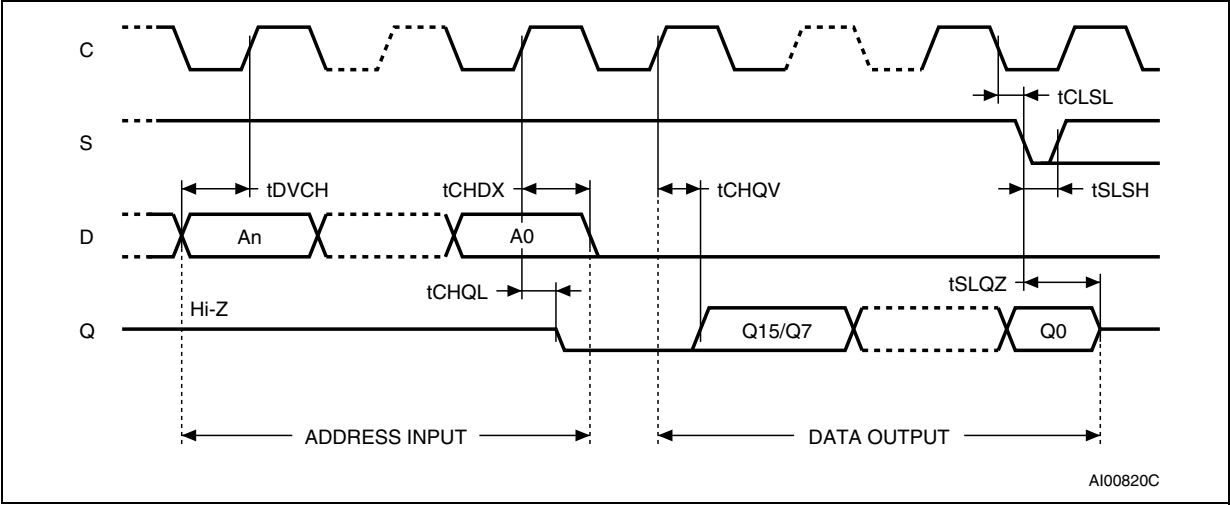
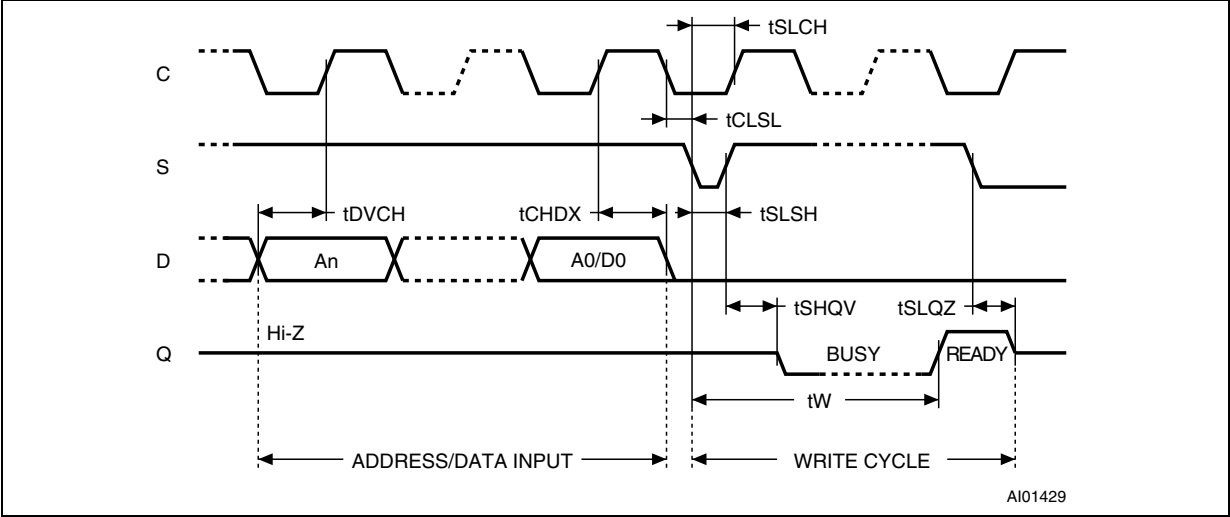


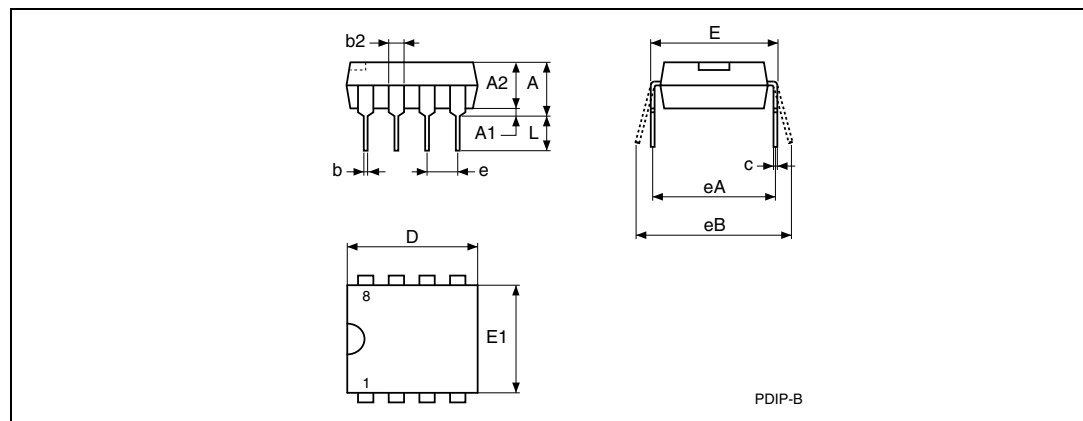
Figure 11. Synchronous timing (Read or Write)



## 12 Package mechanical data

In order to meet environmental requirements, ST offers the M93C86, M93C76, M93C66, M93C56 and M93C46 in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at [www.st.com](http://www.st.com).

**Figure 12. PDIP8 – 8 lead plastic dual in-line package, 300 mils body width, package outline**

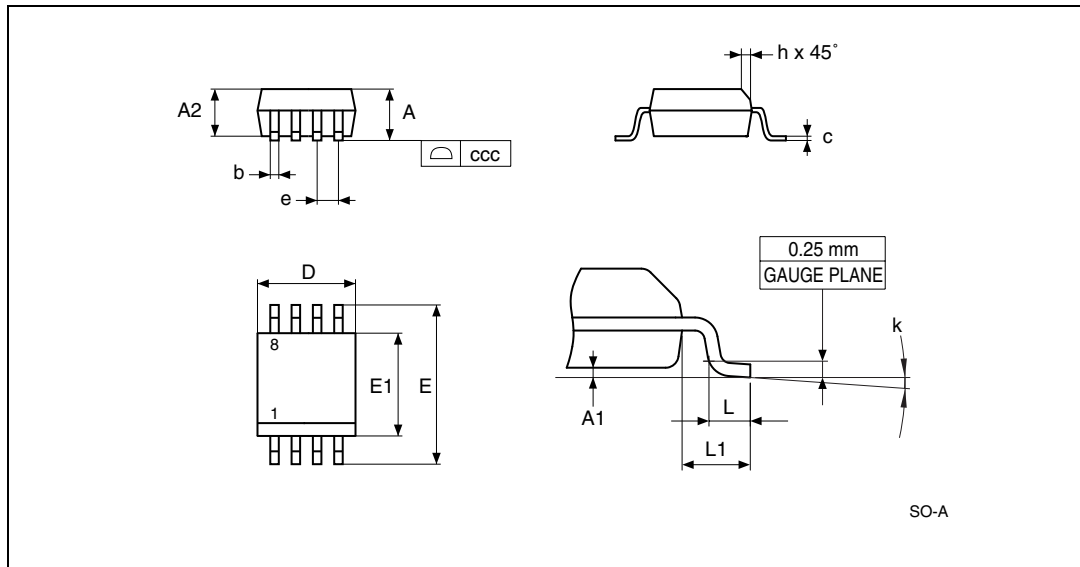


1. Drawing is not to scale.

**Table 24. PDIP8 – 8 lead plastic dual in-line package, 300 mils body width, package mechanical data**

| Symbol | millimeters |      |       | inches <sup>(1)</sup> |        |        |
|--------|-------------|------|-------|-----------------------|--------|--------|
|        | Typ.        | Min. | Max.  | Typ.                  | Min.   | Max.   |
| A      |             |      | 5.33  |                       |        | 0.2098 |
| A1     |             | 0.38 |       |                       | 0.015  |        |
| A2     | 3.3         | 2.92 | 4.95  | 0.1299                | 0.115  | 0.1949 |
| b      | 0.46        | 0.36 | 0.56  | 0.0181                | 0.0142 | 0.022  |
| b2     | 1.52        | 1.14 | 1.78  | 0.0598                | 0.0449 | 0.0701 |
| c      | 0.25        | 0.2  | 0.36  | 0.0098                | 0.0079 | 0.0142 |
| D      | 9.27        | 9.02 | 10.16 | 0.365                 | 0.3551 | 0.4    |
| E      | 7.87        | 7.62 | 8.26  | 0.3098                | 0.3    | 0.3252 |
| E1     | 6.35        | 6.1  | 7.11  | 0.25                  | 0.2402 | 0.2799 |
| e      | 2.54        | -    | -     | 0.1                   | -      | -      |
| eA     | 7.62        | -    | -     | 0.3                   | -      | -      |
| eB     |             |      | 10.92 |                       |        | 0.4299 |
| L      | 3.3         | 2.92 | 3.81  | 0.1299                | 0.115  | 0.15   |

1. Values in inches are converted from mm and rounded to 4 decimal digits.

**Figure 13. SO8 narrow – 8 lead plastic small outline, 150 mils body width, package outline**

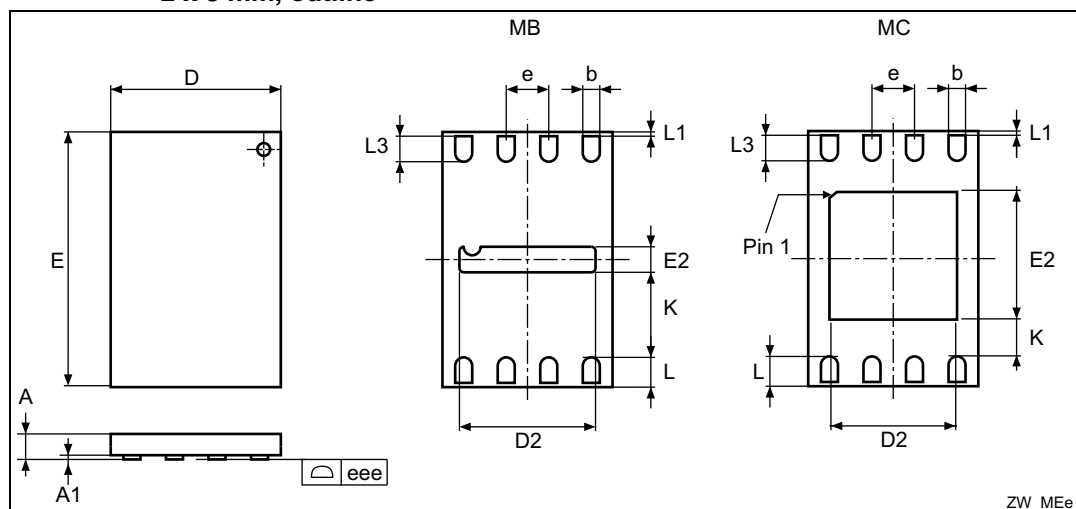
1. Drawing is not to scale.

**Table 25. SO8 narrow – 8 lead plastic small outline, 150 mils body width, package data**

| Symbol | millimeters |      |      | inches <sup>(1)</sup> |        |        |
|--------|-------------|------|------|-----------------------|--------|--------|
|        | Typ         | Min  | Max  | Typ                   | Min    | Max    |
| A      |             |      | 1.75 |                       |        | 0.0689 |
| A1     |             | 0.1  | 0.25 |                       | 0.0039 | 0.0098 |
| A2     |             | 1.25 |      |                       | 0.0492 |        |
| b      |             | 0.28 | 0.48 |                       | 0.011  | 0.0189 |
| c      |             | 0.17 | 0.23 |                       | 0.0067 | 0.0091 |
| ccc    |             |      | 0.1  |                       |        | 0.0039 |
| D      | 4.9         | 4.8  | 5    | 0.1929                | 0.189  | 0.1969 |
| E      | 6           | 5.8  | 6.2  | 0.2362                | 0.2283 | 0.2441 |
| E1     | 3.9         | 3.8  | 4    | 0.1535                | 0.1496 | 0.1575 |
| e      | 1.27        | -    | -    | 0.05                  | -      | -      |
| h      |             | 0.25 | 0.5  |                       | 0.0098 | 0.0197 |
| k      |             | 0°   | 8°   |                       | 0°     | 8°     |
| L      |             | 0.4  | 1.27 |                       | 0.0157 | 0.05   |
| L1     | 1.04        |      |      | 0.0409                |        |        |

1. Values in inches are converted from mm and rounded to 4 decimal digits.

**Figure 14. UFDFPN8 (MLP8) 8-lead ultra thin fine pitch dual flat package no lead  
2 x 3 mm, outline**

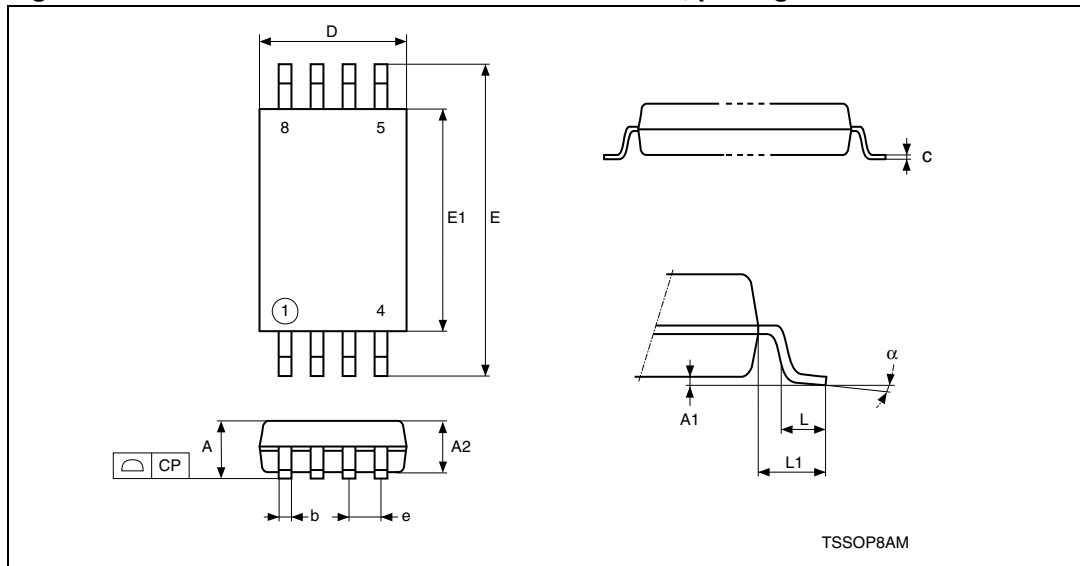


1. Drawing is not to scale.
2. The central pad (area E2 by D2 in the above illustration) is pulled, internally, to  $V_{SS}$ . It must not be allowed to be connected to any other voltage or signal line on the PCB, for example during the soldering process.
3. The circle in the top view of the package indicates the position of pin 1

**Table 26. UFDFPN8 (MLP8) 8-lead ultra thin fine pitch dual flat package no lead  
2 x 3 mm, data**

| Symbol             | millimeters |       |       | inches <sup>(1)</sup> |        |        |
|--------------------|-------------|-------|-------|-----------------------|--------|--------|
|                    | Typ         | Min   | Max   | Typ                   | Min    | Max    |
| A                  | 0.550       | 0.450 | 0.600 | 0.0217                | 0.0177 | 0.0236 |
| A1                 | 0.020       | 0.000 | 0.050 | 0.0008                | 0.0000 | 0.0020 |
| b                  | 0.250       | 0.200 | 0.300 | 0.0098                | 0.0079 | 0.0118 |
| D                  | 2.000       | 1.900 | 2.100 | 0.0787                | 0.0748 | 0.0827 |
| D2 (rev MB)        | 1.600       | 1.500 | 1.700 | 0.0630                | 0.0591 | 0.0669 |
| D2 (rev MC)        |             | 1.200 | 1.600 |                       | 0.0472 | 0.0630 |
| E                  | 3.000       | 2.900 | 3.100 | 0.1181                | 0.1142 | 0.1220 |
| E2 (rev MB)        | 0.200       | 0.100 | 0.300 | 0.0079                | 0.0039 | 0.0118 |
| E2 (rev MC)        |             | 1.200 | 1.600 |                       | 0.0472 | 0.0630 |
| e                  | 0.500       |       |       | 0.0197                |        |        |
| K                  |             | 0.300 |       |                       | 0.0118 |        |
| L                  |             | 0.300 | 0.500 |                       | 0.0118 | 0.0197 |
| L1                 |             |       | 0.150 |                       |        | 0.0059 |
| L3                 |             | 0.300 |       |                       | 0.0118 |        |
| eee <sup>(2)</sup> |             | 0.080 |       |                       | 0.0031 |        |

1. Values in inches are converted from mm and rounded to 4 decimal digits.
2. Applied for exposed die paddle and terminals. Exclude embedding part of exposed die paddle from measuring.

**Figure 15. TSSOP8 – 8 lead thin shrink small outline, package outline**

1. Drawing is not to scale.

**Table 27. TSSOP8 – 8 lead thin shrink small outline, package mechanical data**

| Symbol         | millimeters |      |      | inches <sup>(1)</sup> |        |        |
|----------------|-------------|------|------|-----------------------|--------|--------|
|                | Typ.        | Min. | Max. | Typ.                  | Min.   | Max.   |
| A              |             |      | 1.2  |                       |        | 0.0472 |
| A1             |             | 0.05 | 0.15 |                       | 0.002  | 0.0059 |
| A2             | 1           | 0.8  | 1.05 | 0.0394                | 0.0315 | 0.0413 |
| b              |             | 0.19 | 0.3  |                       | 0.0075 | 0.0118 |
| c              |             | 0.09 | 0.2  |                       | 0.0035 | 0.0079 |
| CP             |             |      | 0.1  |                       |        | 0.0039 |
| D              | 3           | 2.9  | 3.1  | 0.1181                | 0.1142 | 0.122  |
| e              | 0.65        | -    | -    | 0.0256                | -      | -      |
| E              | 6.4         | 6.2  | 6.6  | 0.252                 | 0.2441 | 0.2598 |
| E1             | 4.4         | 4.3  | 4.5  | 0.1732                | 0.1693 | 0.1772 |
| L              | 0.6         | 0.45 | 0.75 | 0.0236                | 0.0177 | 0.0295 |
| L1             | 1           |      |      | 0.0394                |        |        |
| α              |             | 0°   | 8°   |                       | 0°     | 8°     |
| N (pin number) | 8           |      |      | 8                     |        |        |

1. Values in inches are converted from mm and rounded to 4 decimal digits.

## 13 Part numbering

**Table 28. Ordering information scheme**

|                                                                         |        |   |   |    |   |   |   |    |
|-------------------------------------------------------------------------|--------|---|---|----|---|---|---|----|
| Example:                                                                | M93C86 | – | W | MN | 6 | T | P | /S |
| <b>Device type</b>                                                      |        |   |   |    |   |   |   |    |
| M93 = MICROWIRE serial access EEPROM                                    |        |   |   |    |   |   |   |    |
| <b>Device function</b>                                                  |        |   |   |    |   |   |   |    |
| 86 = 16 Kbit (2048 x 8)                                                 |        |   |   |    |   |   |   |    |
| 76 = 8 Kbit (1024 x 8)                                                  |        |   |   |    |   |   |   |    |
| 66 = 4 Kbit (512 x 8)                                                   |        |   |   |    |   |   |   |    |
| 56 = 2 Kbit (256 x 8)                                                   |        |   |   |    |   |   |   |    |
| 46 = 1 Kbit (128 x 8)                                                   |        |   |   |    |   |   |   |    |
| <b>Operating voltage</b>                                                |        |   |   |    |   |   |   |    |
| blank = $V_{CC} = 4.5$ to $5.5$ V                                       |        |   |   |    |   |   |   |    |
| W = $V_{CC} = 2.5$ to $5.5$ V                                           |        |   |   |    |   |   |   |    |
| R = $V_{CC} = 1.8$ to $5.5$ V                                           |        |   |   |    |   |   |   |    |
| <b>Package</b>                                                          |        |   |   |    |   |   |   |    |
| BN = PDIP8                                                              |        |   |   |    |   |   |   |    |
| MN = SO8 (150 mils width)                                               |        |   |   |    |   |   |   |    |
| MB or MC = UFDFPN8 (MLP8)                                               |        |   |   |    |   |   |   |    |
| DW = TSSOP8 (169 mils width)                                            |        |   |   |    |   |   |   |    |
| <b>Device grade</b>                                                     |        |   |   |    |   |   |   |    |
| 6 = Industrial temperature range, $-40$ to $85$ °C.                     |        |   |   |    |   |   |   |    |
| Device tested with standard test flow                                   |        |   |   |    |   |   |   |    |
| 3 = Device tested with high reliability certified flow <sup>(1)</sup> . |        |   |   |    |   |   |   |    |
| Automotive temperature range ( $-40$ to $125$ °C)                       |        |   |   |    |   |   |   |    |
| <b>Packing</b>                                                          |        |   |   |    |   |   |   |    |
| blank = standard packing                                                |        |   |   |    |   |   |   |    |
| T = tape and reel packing                                               |        |   |   |    |   |   |   |    |
| <b>Plating technology</b>                                               |        |   |   |    |   |   |   |    |
| P or G = ECOPACK® (RoHS compliant)                                      |        |   |   |    |   |   |   |    |
| <b>Process<sup>(2)</sup></b>                                            |        |   |   |    |   |   |   |    |
| /S = F6SP36%                                                            |        |   |   |    |   |   |   |    |

1. ST strongly recommends the use of the Automotive Grade devices for use in an automotive environment. The High Reliability Certified Flow (HRCF) is described in the quality note QNEE9801. Please ask your nearest ST sales office for a copy.

2. Used only for device grade 3.

For a list of available options (speed, package, etc.) or for further information on any aspect of this device, please contact your nearest ST sales office.

## 14 Revision history

**Table 29. Document revision history**

| Date        | Revision | Changes                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                               |
|-------------|----------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 04-Feb-2003 | 2.0      | Document reformatted, and reworded, using the new template. Temperature range 1 removed. TSSOP8 (3x3mm) package added. New products, identified by the process letter W, added, with $f_c(\max)$ increased to 1MHz for -R voltage range, and to 2MHz for all other ranges (and corresponding parameters adjusted)                                                                                                                                                                                                                                                                                                                                                                                                     |
| 26-Mar-2003 | 2.1      | Value of standby current (max) corrected in DC characteristics tables for -W and -R ranges<br>$V_{OUT}$ and $V_{IN}$ separated from $V_{IO}$ in the Absolute Maximum Ratings table                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                    |
| 04-Apr-2003 | 2.2      | Values corrected in AC characteristics tables for -W range ( $t_{SLSH}$ , $t_{DVCH}$ , $t_{CLSL}$ ) for devices with Process Identification Letter W                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                  |
| 23-May-2003 | 2.3      | Standby current corrected for -R range                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                |
| 27-May-2003 | 2.4      | Turned-die option re-instated in Ordering Information Scheme                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                          |
| 25-Nov-2003 | 3.0      | Table of contents, and Pb-free options added. Temperature range 7 added. $V_{IL}(\min)$ improved to -0.45V.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           |
| 30-Mar-2004 | 4.0      | MLP package added. Absolute Maximum Ratings for $V_{IO}(\min)$ and $V_{CC}(\min)$ changed. Soldering temperature information clarified for RoHS compliant devices. Device grade information clarified. Process identification letter "G" information added                                                                                                                                                                                                                                                                                                                                                                                                                                                            |
| 16-Aug-2004 | 5.0      | M93C06 removed. Device grade information further clarified. Process identification letter "S" information added. Turned-die package option removed. Product list summary added.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                       |
| 27-Oct-2005 | 6.0      | current product/new product distinction removed. $I_{CC}$ and $I_{CC1}$ values for current product removed from tables 15, 16 and 17 and AC characteristics for current product removed from Tables 20 and 21. Clock rate added to Features.<br>"Q = open" added to $I_{CC}$ Test conditions in DC Characteristics Tables 15, 16, 17, 18 and 19.<br><i>Process</i> added to <i>Table 28.: Ordering information scheme</i> . POWER ON DATA PROTECTION section removed, replaced by <i>Operating features</i> and <i>Active Power and Standby Power modes</i> . <i>Initial delivery state</i> added.<br>SO8N and TSSOP8 packages updated. PDIP-specific $T_{LEAD}$ added to <i>Table 8.: Absolute maximum ratings</i> . |



Table 29. Document revision history (continued)

| Date        | Revision | Changes                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           |
|-------------|----------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 31-Jul-2007 | 7        | <p>Document reformatted. TSSOP8 3 × 3 mm (DS) package removed.</p> <p>Erase/Write Enable (EWEN) instruction replaced by Write Enable (WEN). Erase/Write Disable (EWDS) instruction replaced by Write Disable (WDS).</p> <p><a href="#">Section 7: Initial delivery state</a> modified, ACTIVE POWER AND STANDBY POWER MODES section removed.</p> <p>I<sub>CC1</sub> test conditions modified in <a href="#">Table 15</a>, <a href="#">Table 16</a>, <a href="#">Table 17</a>, <a href="#">Table 18</a> and <a href="#">Table 19</a>. Note 1 added to <a href="#">Table 15</a>.</p> <p>t<sub>W</sub> parameter description modified in <a href="#">Table 20</a>, <a href="#">Table 21</a>, <a href="#">Table 22</a> and <a href="#">Table 23</a>.</p> <p>SO8 narrow and UDFPN8 package specifications updated (see <a href="#">Section 12: Package mechanical data</a>).</p> <p><a href="#">Table 29</a>, <a href="#">Table 30</a>, <a href="#">Table 31</a>, <a href="#">Table 32</a> and <a href="#">Table 33</a> added.</p> <p>Blank option removed under Plating technology in <a href="#">Table 27: TSSOP8 – 8 lead thin shrink small outline, package mechanical data</a>.</p> <p><a href="#">Section 2: Connecting to the serial bus</a> added. Device grade 7 removed.</p> |
| 29-Jan-2008 | 8        | <p>Small text changes.</p> <p>M93C76-R root part number added.</p> <p><a href="#">Section 2: Connecting to the serial bus</a> modified (pull-down resistor added to <a href="#">Figure 3: Bus master and memory devices on the serial bus</a> and paragraph added).</p> <p><a href="#">Section 3.1.2: Power-up conditions</a> corrected.</p> <p>T<sub>LEAD</sub> modified in <a href="#">Table 8: Absolute maximum ratings</a>.</p> <p>V<sub>OH</sub> min guaranteed at a higher value in DC characteristics tables <a href="#">15</a>, <a href="#">16</a>, <a href="#">17</a> and <a href="#">18</a>.</p> <p>M93C56-R is also offered in TSSOP8 package (see <a href="#">Table 30</a>).</p> <p>Package mechanical inch values calculated from mm and rounded to 4 decimal digits in <a href="#">Section 12: Package mechanical data</a></p> <p>TSSOP8 (DW) package specifications updated.</p>                                                                                                                                                                                                                                                                                                                                                                                   |
| 01-Apr-2010 | 9        | <p>Modified footnote in <a href="#">Table 15</a> and <a href="#">Table 16 on page 21</a></p> <p>Updated <a href="#">Figure 14: UDFPN8 (MLP8) 8-lead ultra thin fine pitch dual flat package no lead 2 x 3 mm, outline</a> and <a href="#">Table 26: UDFPN8 (MLP8) 8-lead ultra thin fine pitch dual flat package no lead 2 x 3 mm, data</a></p>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   |
| 29-Apr-2010 | 10       | <p>Updated <a href="#">Figure 31: Available M93C66-x products (package, voltage range, temperature grade)</a> UDFPN option.</p>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   |
| 12-Apr-2011 | 11       | <p>Updated <a href="#">Table 8: Absolute maximum ratings</a>, MLP8 package data in <a href="#">Section 12: Package mechanical data</a> and process data in <a href="#">Section 9: Clock pulse counter</a>.</p> <p>Deleted <a href="#">Table 29: Available M93C46-x products (package, voltage range, temperature grade)</a>, <a href="#">Table 30: Available M93C56-x products (package, voltage range, temperature grade)</a>, <a href="#">Table 31: Available M93C66-x products (package, voltage range, temperature grade)</a>, <a href="#">Table 32: Available M93C76-x products (package, voltage range, temperature grade)</a> and <a href="#">Table 33: Available M93C86-x products (package, voltage range, temperature grade)</a>.</p>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   |
| 05-Oct-2011 | 12       | <p>Updated <a href="#">Table 1: Device summary</a> and <a href="#">Table 9: Operating conditions (M93Cx6)</a>.</p> <p>Modified footnote 2 in <a href="#">Table 8</a>.</p>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                         |

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Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

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